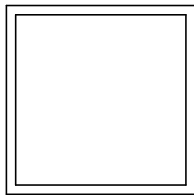
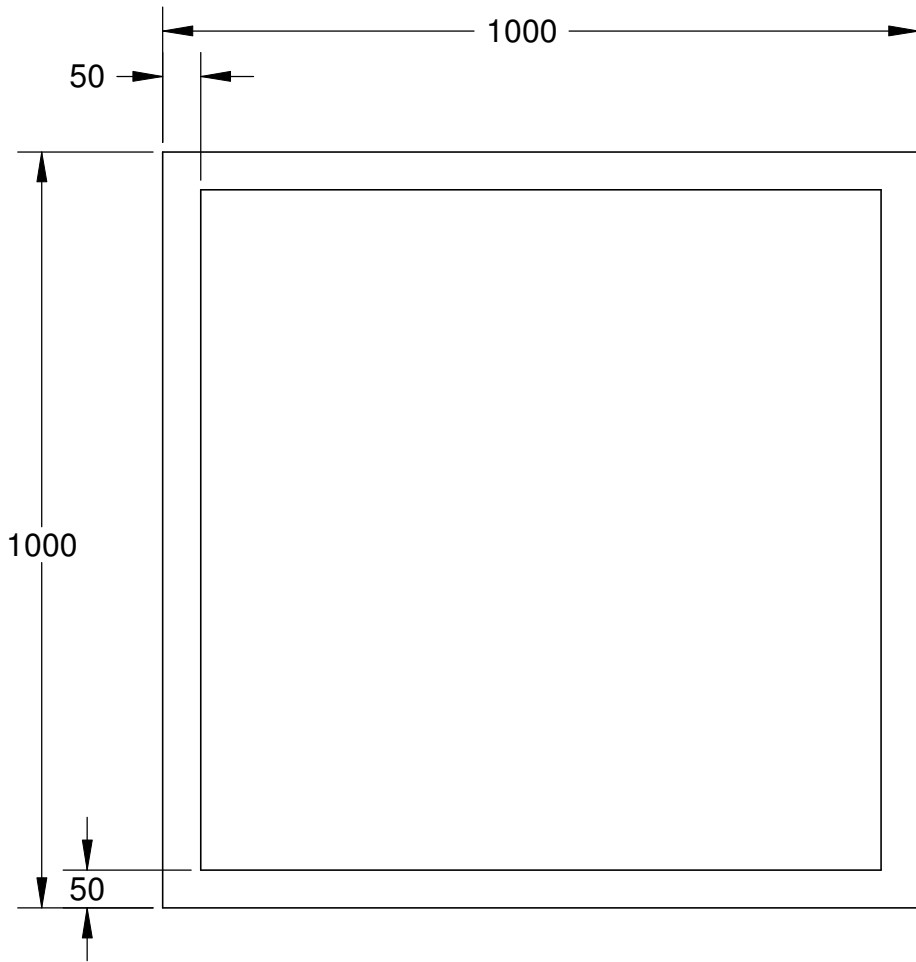


REVISIONS				
DATE	REV.	ECO	DESCRIPTION	APPROVED



SCALE 25:1

Notes: (Unless Otherwise Specified).

- 1) DIE MATERIAL IS SILICON.
- 2) DIE THICKNESS IS 250 μm (10 MIL).
- 3) METALLIZATION 1.0 μm ALUMINUM (Al) OVER 0.75 μm SiO_2 .
- 4) DIE IS WITHOUT PASSIVATION.
- 5) WIRE BONDABLE WITH GOLD (Au) OR ALUMINUM (Al) WIRE.
- 6) FULLY METALLIZED OVER ENTIRE SURFACE OF DIE.
- 7) TOLERANCE = $\pm 1 \mu\text{m}$.

DIMENSIONS IN MICRONS
1000 μm = 1.0mm

PART NUMBER SYSTEM				
TD	-	1	-	BUS
SILICON TEST DIE		BOND PADS	DIE SIZE (mm)	FULLY METALLIZED

TOLERANCE UNLESS NOTED	
X.XX	+/- 0.01
X.XXX	+/- 0.005
X.XXXX	+/- 0.0005
ANGLES	+/- 0.5°
ALL DIMENSIONS IN	
<input checked="" type="checkbox"/> INCHES	<input type="checkbox"/> MILLIMETERS
THIRD ANGLE PROJECTION	

APPROVALS	DATE
DRAWN J. HINES	5/2/2010
ENG	
MFG	
QA	
CUST	
REVISED	

TITLE			
Si TEST DIE TD SERIES			
SCALE	SIZE	DRAWING NO.	REV
100:1	A	151001	A
DO NOT SCALE DRAWING		SHEET 1 OF 1	